

		Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	4726	trench with gate	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:37				0
2	BRS	L2	4864	trench with gate\$1	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:40				0
3	BRS	L3	289	2 and ("on resistance" or "on-resistance")	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:39				0
4	BRS	L4	8	2 and ("bi-directional")	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:39				0
5	BRS	L5	679	2 and (gate with doped with polysilicon)	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:40				0
6	BRS	L6	397	5 and (gate with type)	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:41				0
7	BRS	L7	706	2 and (gate with conductivity with type)	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:42				0
8	BRS	L8	69	2 and (gate with conductivity with type with polysilicon)	USPAT; ; EPO; JPO; Derwe nt; IBM TDB	2001/01/24 13:42				0